Dual low-ohmic single-pole single-throw analog switch

Rev. 3 — 7 November 2011

Product data sheet

1. General description

The NX3L2T384 is a dual low-ohmic single-pole single-throw analog switch. Each switch has two input/output terminals (nY and nZ) and an active LOW enable input (n \overline{E}). When pin n \overline{E} is HIGH, the analog switch is turned off.

Schmitt trigger action at the enable input $(n\overline{E})$ makes the circuit tolerant to slower input rise and fall times. A low input voltage threshold allows pin nE to be driven by lower level logic signals without a significant increase in supply current I_{CC}. This makes it possible for the NX3L2T384 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation.

The NX3L2T384 allows signals with amplitude up to V_{CC} to be transmitted from nY to nZ; or from nZ to nY. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.6 Ω (typical) at V_{CC} = 1.4 V
 - 1.0 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 7500 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - IEC61000-4-2 contact discharge exceeds 4000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78B Class II Level A
- 1.8 V control logic at V_{CC} = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



Dual low-ohmic single-pole single-throw analog switch

Applications 3.

- Cell phone
- PDA
- Portable media player

Ordering information 4.

Table 1. **Ordering information**

Type number	Package						
	Temperature range	Name	Description	Version			
NX3L2T384GT	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 \times 1.95 \times 0.5 mm	SOT833-1			
NX3L2T384GD	–40 °C to +125 °C	XSON8U	plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body $3 \times 2 \times 0.5$ mm	SOT996-2			
NX3L2T384GM	–40 °C to +125 °C	XQFN8	plastic extremely thin quad flat package; no leads; 8 terminals; body $1.6 \times 1.6 \times 0.5$ mm	SOT902-1			

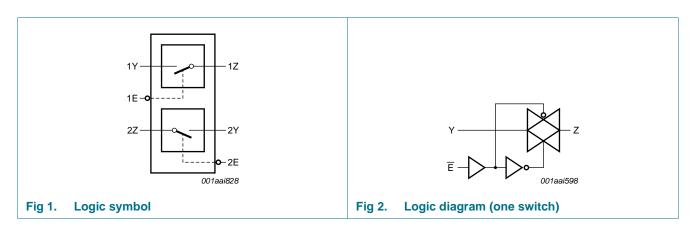
Marking 5.

Table 2.	Marking	codes ^[1]
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Type number	Marking code
NX3L2T384GT	M84
NX3L2T384GD	M84
NX3L2T384GM	M84

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

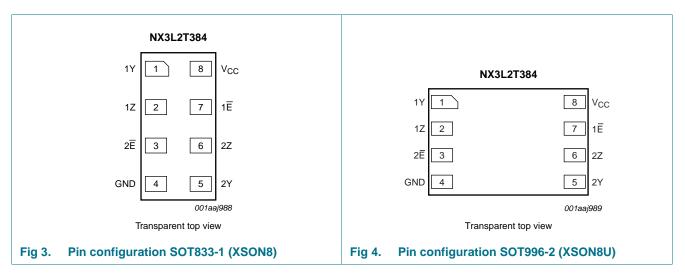
Functional diagram 6.

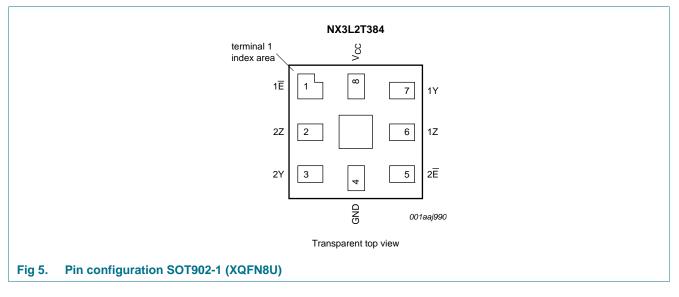


Dual low-ohmic single-pole single-throw analog switch

7. Pinning information

7.1 Pinning





7.2 Pin description

Symbol	Pin		Description
	SOT833-1 and SOT996-2	SOT902-1	
1Y, 2Y	1, 5	7, 3	independent input or output
1Z, 2Z	2, 6	6, 2	independent input or output
GND	4	4	ground (0 V)
1 <u>E</u> , 2 <u>E</u>	7, 3	1, 5	enable input (active HIGH)
V _{CC}	8	8	supply voltage

Product data sheet

Dual low-ohmic single-pole single-throw analog switch

8. Functional description

	Function table ^[1]	
Input nE	E Switch	
L	ON-state	
Н	OFF-state	

[1] H = HIGH voltage level; L = LOW voltage level.

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	enable input nE	<u>[1]</u> –0.5	+4.6	V
V _{SW}	switch voltage		[2] -0.5	$V_{CC} + 0.5$	V
I _{IK}	input clamping current	V _I < -0.5 V	-50	-	mA
I _{SK}	switch clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	-	±50	mA
I _{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	-	±350	mA
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[3] _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For XSON8, XSON8U and XQFN8U packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		1.4	-	4.3	V
VI	input voltage	enable input nE	0	-	4.3	V
V _{SW}	switch voltage		<u>[1]</u> 0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.4 V to 4.3 V	[2] _	-	200	ns/V

[1] To avoid sinking GND current from terminal nZ when switch current flows in terminal nY, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no GND current will flow from terminal nY. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

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Dual low-ohmic single-pole single-throw analog switch

11. Static characteristics

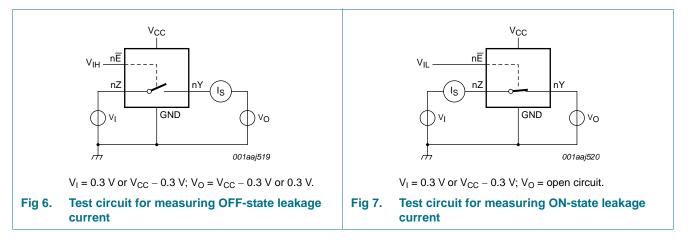
Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} = -40 °C to +125 °C			Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
VIH	HIGH-level	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	0.9	-	-	0.9	-	-	V
input voltage	input voltage	$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	0.9	-	-	0.9	-	-	V
	V_{CC} = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V	
	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	1.3	-	-	1.3	-	-	V	
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	1.4	-	-	1.4	-	-	V
V _{IL}	LOW-level	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	-	0.3	-	0.3	0.3	V
	input voltage	V_{CC} = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.5	-	0.5	0.5	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	0.6	-	0.6	0.6	V
I	input leakage current	enable input $n\overline{E}$; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
I _{S(OFF)}	OFF-state	nY port; see <u>Figure 6</u>							
leakage		$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	-	±10	-	±50	±500	nA
I _{S(ON)}	ON-state	nZ port; see <u>Figure 7</u>							
	leakage	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	-	±10	-	±50	±500	nA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}							
		$V_{CC} = 3.6 V$	-	-	100	-	690	6000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	7000	nA
ΔI_{CC}	additional	V_{SW} = GND or V_{CC}							
	supply current	$V_1 = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	2.0	4.0	-	7	7	μA
		$V_1 = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	0.35	0.7	-	1	1	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	7.0	10.0	-	15	15	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	2.5	4.0	-	5	5	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$	-	50	200	-	300	500	nA
CI	input capacitance		-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
C _{S(ON)}	ON-state capacitance		-	110	-	-	-	-	pF

Dual low-ohmic single-pole single-throw analog switch

11.1 Test circuits



11.2 ON resistance

Table 8.ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 9 to Figure 15.

Symbol	Parameter	Conditions	T _{amb}	= -40 °C to	o +85 ℃	$T_{amb} = -40$ °	Unit	
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	$V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$; see <u>Figure 8</u>						
		$V_{CC} = 1.4 V$	-	1.6	3.7	-	4.1	Ω
		V _{CC} = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
ΔR_{ON}	ON resistance mismatch between channels	$V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$	[2]					
		$V_{CC} = 1.4 V$	-	0.04	0.3	-	0.3	Ω
		V _{CC} = 1.65 V	-	0.04	0.2	-	0.3	Ω
		$V_{CC} = 2.3 V$	-	0.02	0.08	-	0.1	Ω
		$V_{CC} = 2.7 V$	-	0.02	0.075	-	0.1	Ω
		$V_{CC} = 4.3 V$	-	0.02	0.075	-	0.1	Ω
R _{ON(flat)}	ON resistance (flatness)	$V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$	[3]					
		$V_{CC} = 1.4 V$	-	1.0	3.3	-	3.6	Ω
		V _{CC} = 1.65 V	-	0.5	1.2	-	1.3	Ω
		$V_{CC} = 2.3 V$	-	0.15	0.3	-	0.35	Ω
		$V_{CC} = 2.7 V$	-	0.13	0.3	-	0.35	Ω
		$V_{CC} = 4.3 V$	-	0.2	0.4	-	0.45	Ω

[1] Typical values are measured at T_{amb} = 25 °C.

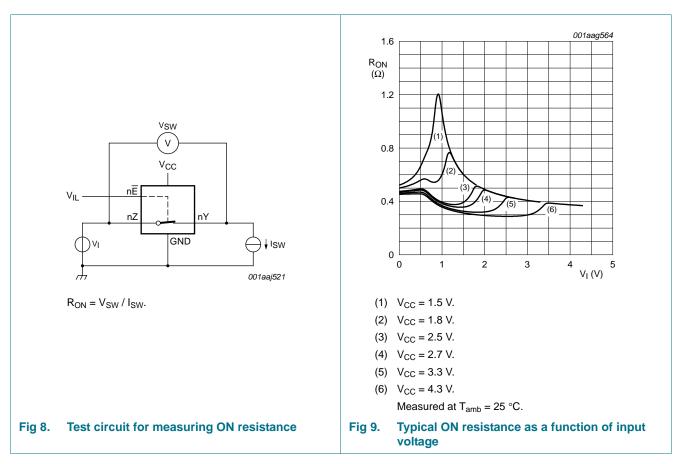
[2] Measured at identical V_{CC} , temperature and input voltage.

6 of 20

NX3L2T384

Dual low-ohmic single-pole single-throw analog switch

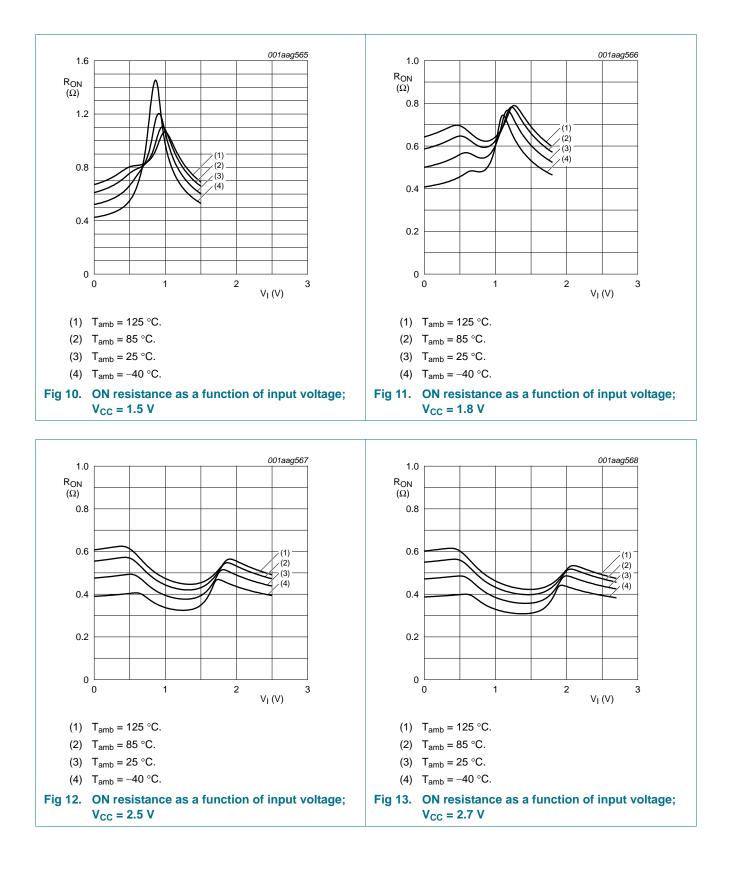
[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.



11.3 ON resistance test circuit and graphs

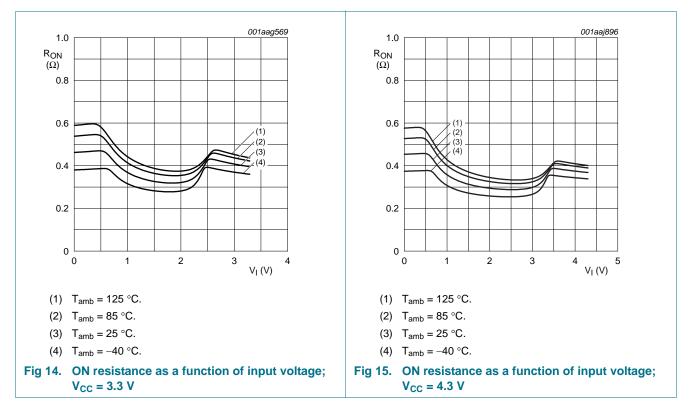
NX3L2T384

Dual low-ohmic single-pole single-throw analog switch



NX3L2T384

Dual low-ohmic single-pole single-throw analog switch



12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} = -40 °C to +125 °C			Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	nE to nZ or nY; see <u>Figure 16</u>							
		V_{CC} = 1.4 V to 1.6 V	-	50	90	-	120	120	ns
		V_{CC} = 1.65 V to 1.95 V	-	36	70	-	80	90	ns
		V_{CC} = 2.3 V to 2.7 V	-	24	45	-	50	55	ns
		V_{CC} = 2.7 V to 3.6 V	-	22	40	-	45	50	ns
		V_{CC} = 3.6 V to 4.3 V	-	22	40	-	45	50	ns
t _{dis}	disable time	nĒ to nZ or nY; see <u>Figure 16</u>							
		V_{CC} = 1.4 V to 1.6 V	-	30	45	-	50	60	ns
		V_{CC} = 1.65 V to 1.95 V	-	20	30	-	35	40	ns
		V_{CC} = 2.3 V to 2.7 V	-	15	20	-	22	25	ns
		V_{CC} = 2.7 V to 3.6 V	-	11	15	-	18	22	ns
		V_{CC} = 3.6 V to 4.3 V	-	11	15	-	18	22	ns

[1] Typical values are measured at $T_{amb} = 25$ °C and $V_{CC} = 1.5$ V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

Dual low-ohmic single-pole single-throw analog switch

12.1 Waveform and test circuits

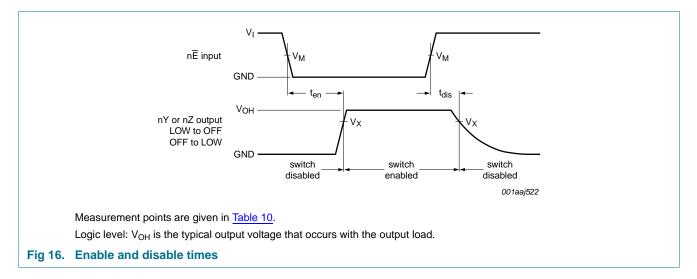


Table 10.Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	Vx
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

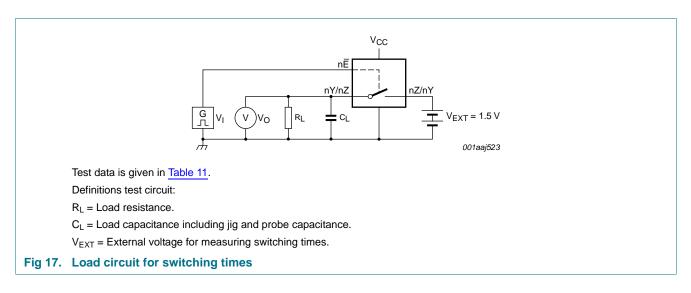


Table 11. Test data

Supply voltage	Input		Load	
V _{cc}	VI	t _r , t _f	CL	R _L
1.4 V to 4.3 V	V _{CC}	\leq 2.5 ns	35 pF	50 Ω

NX3L2T384 Product data sheet

12.2 Additional dynamic characteristics

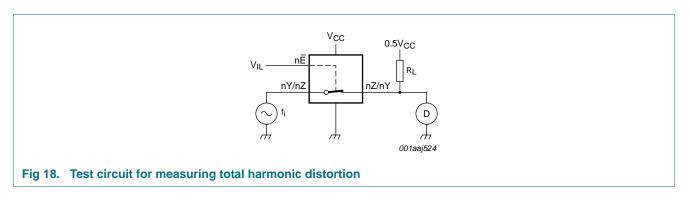
Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns.

Symbol	Parameter	Conditions	T _{amb} = 25 °C			Unit	
				Min	Тур	Max	
THD	total harmonic distortion	$f_i = 20$ Hz to 20 kHz; $R_L = 32 \Omega$; see Figure 18	<u>[1]</u>				
		V _{CC} = 1.4 V; V _I = 1 V (p-p)		-	0.15	-	%
		V _{CC} = 1.65 V; V _I = 1.2 V (p-p)		-	0.10	-	%
		V _{CC} = 2.3 V; V _I = 1.5 V (p-p)		-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$		-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$		-	0.02	-	%
f _(-3dB)	–3 dB frequency response	$R_L = 50 \Omega$; see <u>Figure 19</u>	<u>[1]</u>				
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$		-	60	-	MHz
$\alpha_{\sf iso}$	isolation (OFF-state)	$f_i = 100 \text{ kHz}; \text{ R}_L = 50 \Omega; \text{ see } \frac{\text{Figure 20}}{1000 \text{ kHz}}$	[1]				
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$		-	-90	-	dB
V _{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 21					
		$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$		-	0.2	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$		-	0.2	-	V
Xtalk	crosstalk	between switches; $f_i = 100 \text{ kHz}$; $R_L = 50 \Omega$; see <u>Figure 22</u>	<u>[1]</u>				
		$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$		-	-90	-	dB
Q _{inj}	charge injection	$f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure 23}}{2}$					
		$V_{CC} = 1.5 V$		-	3	-	рС
		V _{CC} = 1.8 V		-	3	-	рС
		$V_{CC} = 2.5 V$		-	3	-	рС
		$V_{CC} = 3.3 V$		-	3	-	рС
		$V_{CC} = 4.3 V$		-	6	-	рС

[1] f_i is biased at 0.5V_{CC}.

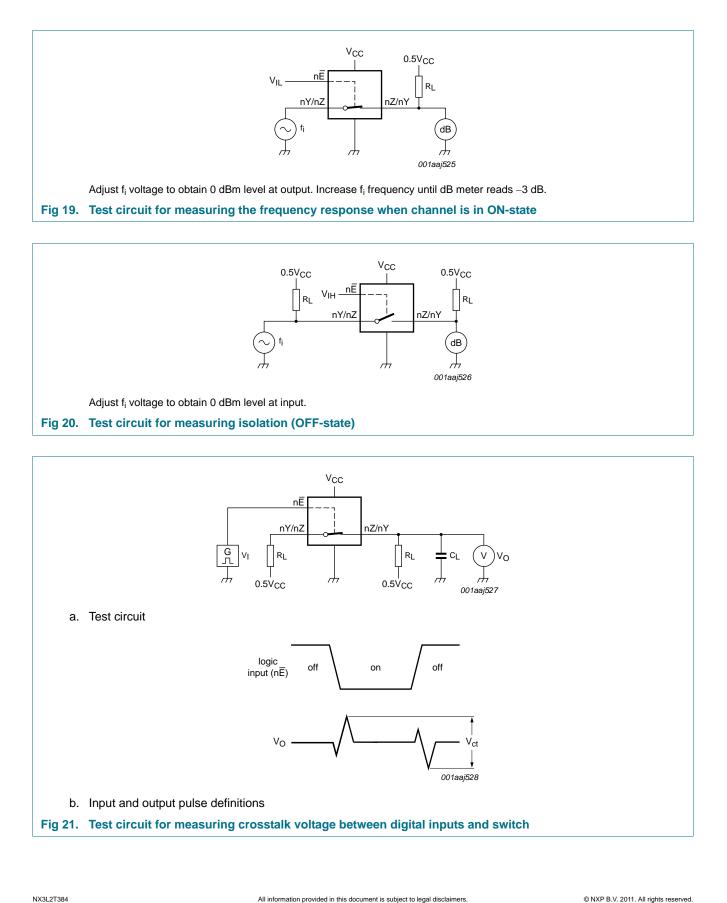
13. Test circuits



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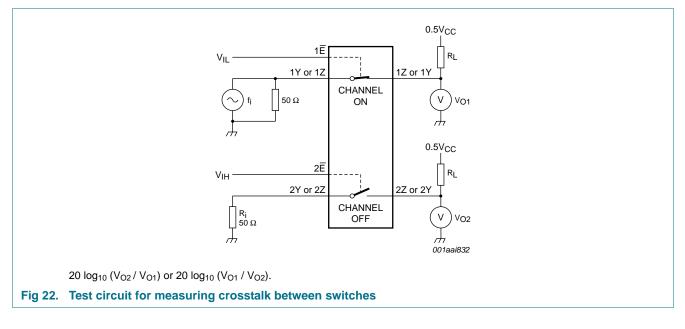
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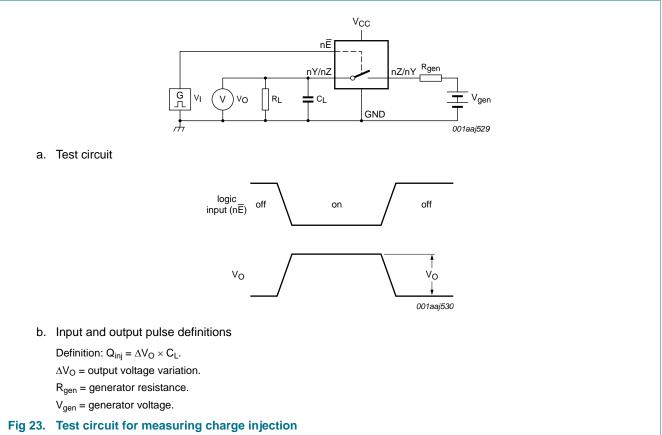
Dual low-ohmic single-pole single-throw analog switch



NX3L2T384

Dual low-ohmic single-pole single-throw analog switch





Dual low-ohmic single-pole single-throw analog switch

14. Package outline

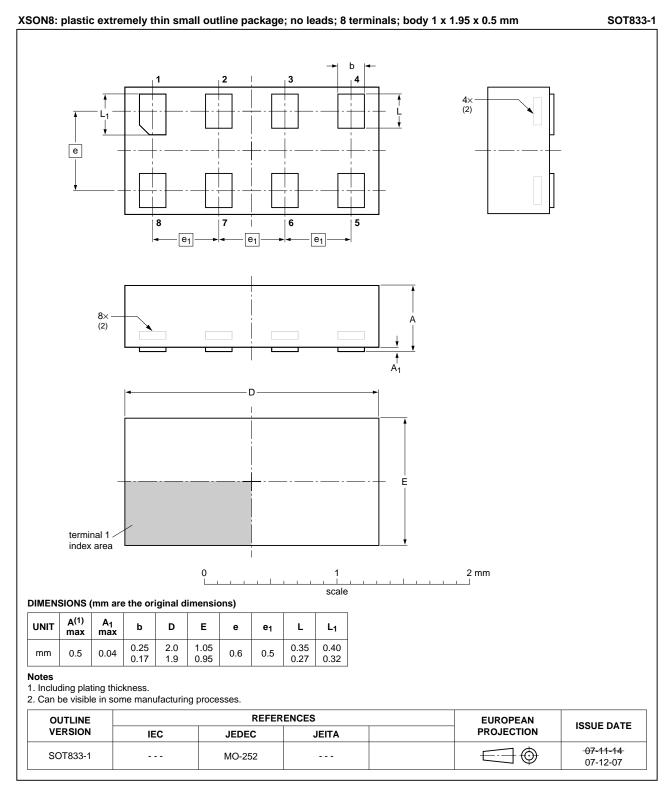
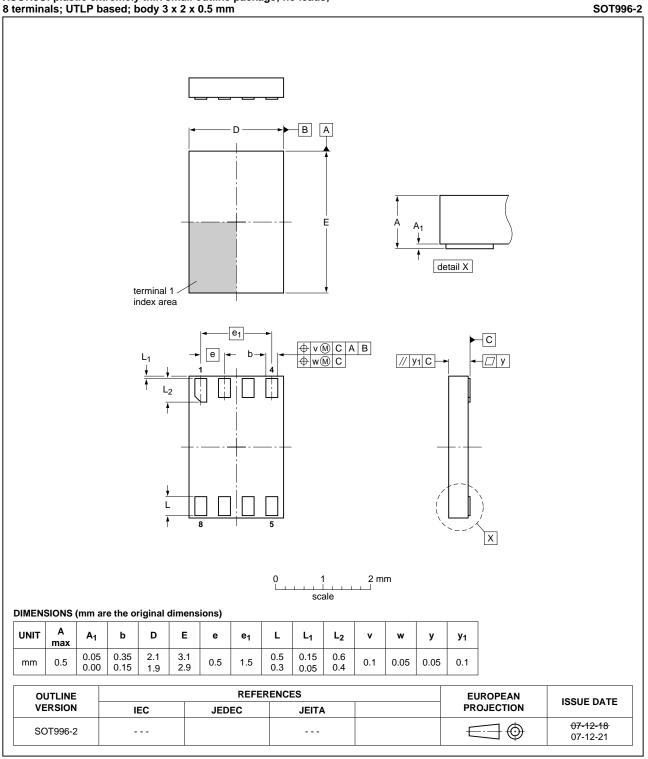


Fig 24. Package outline SOT833-1 (XSON8)

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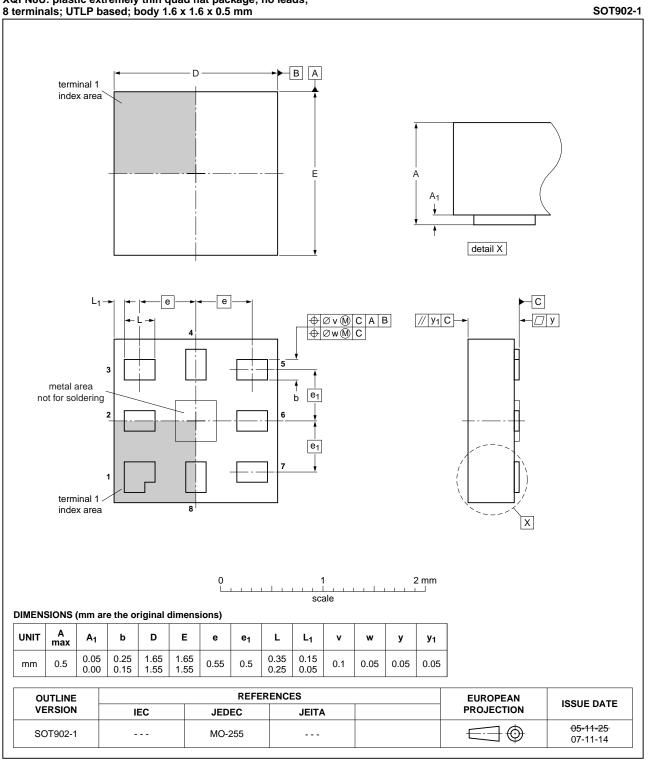


XSON8U: plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body 3 x 2 x 0.5 mm

Fig 25. Package outline SOT996-2 (XSON8U)

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Dual low-ohmic single-pole single-throw analog switch



XQFN8U: plastic extremely thin quad flat package; no leads; 8 terminals; UTLP based; body 1.6 x 1.6 x 0.5 mm

Fig 26. Package outline SOT902-1 (XQFN8U)

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Dual low-ohmic single-pole single-throw analog switch

15. Abbreviations

Table 13. Abbreviations			
Acronym	Description		
CDM	Charged Device Model		
CMOS	Complementary Metal Oxide Semiconductor		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
MM	Machine Model		

16. Revision history

Table 14.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L2T384 v.3	20111107	Product data sheet	-	NX3L2T384 v.2
Modifications:	 Legal pages 	updated.		
NX3L2T384 v.2	20101221	Product data sheet	-	NX3L2T384 v.1
NX3L2T384 v.1	20091022	Product data sheet	-	-

Dual low-ohmic single-pole single-throw analog switch

17. Legal information

17.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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19. Contents

1	General description 1
2	Features and benefits 1
3	Applications
4	Ordering information 2
5	Marking 2
6	Functional diagram 2
7	Pinning information 3
7.1	Pinning 3
7.2	Pin description 3
8	Functional description 4
9	Limiting values 4
10	Recommended operating conditions 4
11	Static characteristics 5
11.1	Test circuits 6
11.2	ON resistance 6
11.3	ON resistance test circuit and graphs7
12	Dynamic characteristics 9
12.1	Waveform and test circuits 10
12.2	Additional dynamic characteristics 11
13	Test circuits 11
14	Package outline 14
15	Abbreviations 17
16	Revision history 17
17	Legal information
17.1	Data sheet status 18
17.2	Definitions
17.3	Disclaimers
17.4	Trademarks 19
18	Contact information 19
19	Contents

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